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2SA1943/FJL4215 **PNP Epitaxial Silicon Transistor**

Applications

- · High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: I_C = -17A.
- High Power Dissipation: 150watts.
- High Frequency: 30MHz.
- High Voltage : V_{CEO}= -250V
- · Wide S.O.A for reliable operation.
- · Excellent Gain Linearity for low THD.
- Complement to 2SC5200/FJL4315.
- Full thermal and electrical Spice models are available.
- Same transistor is also available in:
 - -- TO3P package, 2SA1962/FJA4213: 130 watts
 - -- TO220 package, FJP1943: 80 watts
 - -- TO220F package, FJPF1943: 50 watts



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* Ta = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV _{CBO}	Collector-Base Voltage	-250	V	
BV _{CEO}	Collector-Emitter Voltage	-250	V	
BV _{EBO}	Emitter-Base Voltage	-5	V	
I _C	Collector Current	-17	А	
I _B	Base Current	-1.5	А	
P _D	Total Device Dissipation(T _C =25°C) Derate above 25°C	150 1.04	W W/°C	
T _J , T _{STG}	Junction and Storage Temperature	- 50 ~ +150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.83	°C/W	

^{*} Device mounted on minimum pad size

h_{FE} Classification

Classification	R	0
h _{FE1}	55 ~ 110	80 ~ 160

$\textbf{Electrical Characteristics*} \ \, \textbf{T}_{a}\text{=-}25^{\circ}\text{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =-5mA, I _E =0	-250			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =-10mA, R _{BE} =∞	-250			٧
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =-5mA, I _C =0	-5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =-230V, I _E =0			-5.0	μА
I _{EBO}	Emitter Cut-off Current	V_{EB} =-5V, I_{C} =0			-5.0	μΑ
h _{FE1}	DC Current Gain	V _{CE} =-5V, I _C =-1A	55		160	
h _{FE2}	DC Current Gain	V _{CE} =-5V, I _C =-7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =-8A, I _B =-0.8A		-0.4	-3.0	٧
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =-5V, I _C =-7A		-1.0	-1.5	٧
f _T	Current Gain Bandwidth Product	V _{CE} =-5V, I _C =-1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =-10V, f=1MHz		360		pF

^{*} Pulse Test: Pulse Width=20 μ s, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
2SA1943RTU	A1943R	TO-264	TUBE	hFE1 R grade
2SA1943OTU	A1943O	TO-264	TUBE	hFE1 O grade
FJL4215RTU	J4215R	TO-264	TUBE	hFE1 R grade
FJL4215OTU	J4215O	TO-264	TUBE	hFE1 O grade

Typical Characteristics

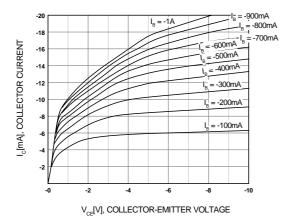


Figure 1. Static Characteristic

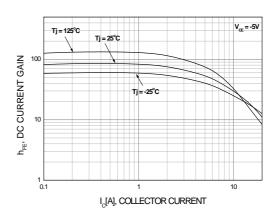


Figure 2. DC current Gain (R Grade)

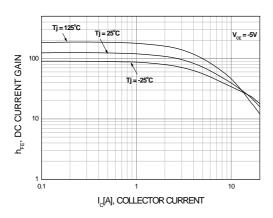


Figure 3. DC current Gain (O Grade)

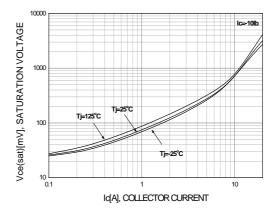


Figure 4. Collector-Emitter Saturation Voltage

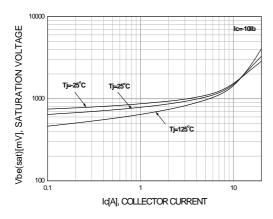


Figure 5. Base-Emitter Saturation Voltage

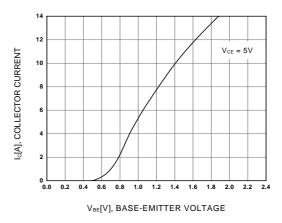


Figure 6. Base-Emitter On Voltage

Typical Characteristics

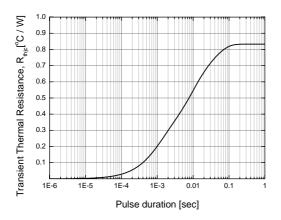


Figure 7. Thermal Resistance

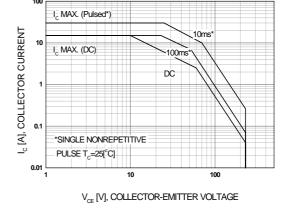


Figure 8. Safe Operating Area

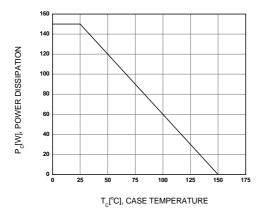
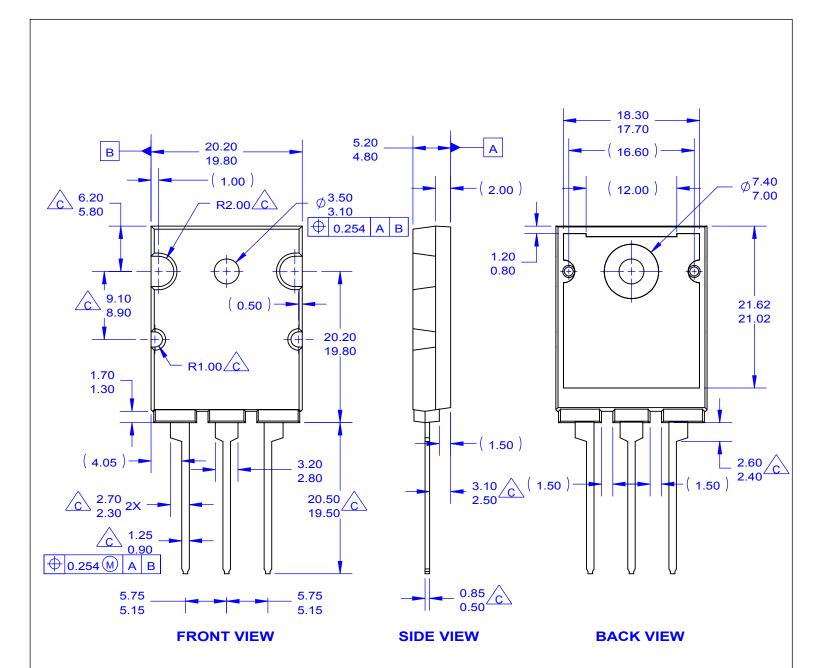
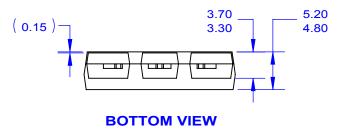


Figure 9. Power Derating







NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C OUT OF JEDEC STANDARD VALUE.
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